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April 1st, 2010 Renesas Electronics Corporation

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MOS FIELD EFFECT TRANSISTOR μ PA2211T1M

P-CHANNEL MOS FET FOR SWITCHING

DESCRIPTION

The μ PA2211T1M is P-channel MOS Field Effect Transistor designed for power management applications of portable equipments, such as load switch.

FEATURES

• Low on-state resistance

 $R_{DS(on)1} = 25 \text{ m}\Omega \text{ MAX.} (V_{GS} = -4.5 \text{ V}, I_D = -7.5 \text{ A})$

 $R_{DS(on)2}$ = 34 m Ω MAX. (Vgs = -2.5 V, ID = -3.8 A)

 $R_{DS(on)3} = 66 \text{ m}\Omega \text{ MAX.} \text{ (Vgs} = -1.8 \text{ V, Ip} = -3.8 \text{ A)}$

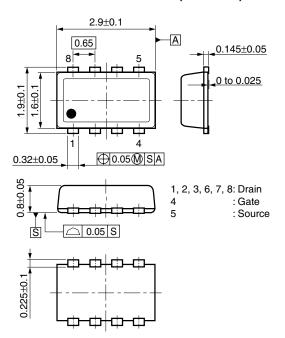
- Built-in gate protection diode
- −1.8 V Gate drive available

ORDERING INFORMATION

| PART NUMBER | PACKING | PACKAGE |
|-----------------------|----------------------|-------------------|
| μPA2211T1M-T1-AT Note | 8 mm embossed taping | 8-pin VSOF (1629) |
| μPA2211T1M-T2-AT Note | 3000 p/reel | 0.011 g TYP. |

Note Pb-free (This product does not contain Pb in external electrode and other parts.)

PACKAGE DRAWING (Unit: mm)



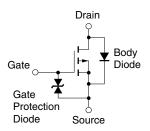
ABSOLUTE MAXIMUM RATINGS (TA = 25°C, All terminals are connected.)

| Drain to Source Voltage (Vgs = 0 V) | VDSS | -12 | V |
|--|-----------------|------------------|----|
| Gate to Source Voltage (V _{DS} = 0 V) | Vgss | ∓8 | V |
| Drain Current (DC) | $I_{D(DC)}$ | ∓ 7.5 | Α |
| Drain Current (pulse) Note1 | $I_{D(pulse)}$ | ∓30 | Α |
| Total Power Dissipation Note2 | P _{T1} | 1.1 | W |
| Total Power Dissipation (PW = 5 sec) Note2 | P _{T2} | 2.5 | W |
| Channel Temperature | Tch | 150 | °C |
| Storage Temperature | Tstg | -55 to +150 | °C |
| | | | |

Notes 1. PW \leq 10 μ s, Duty Cycle \leq 1%

2. Mounted on glass epoxy board of 25.4 mm x 25.4 mm x 0.8 mmt

EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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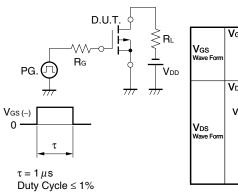
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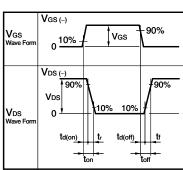
ELECTRICAL CHARACTERISTICS (TA = 25°C, All terminals are connected.)

| CHARACTERISTICS | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--|----------------------|---|-------|-------|------|------|
| Zero Gate Voltage Drain Current | IDSS | V _{DS} = -12 V, V _{GS} = 0 V | | | -10 | μΑ |
| Gate Leakage Current | Igss | V _{GS} = ∓8 V, V _{DS} = 0 V | | | ∓10 | μA |
| Gate to Source Cut-off Voltage | V _{GS(off)} | V _{DS} = -10 V, I _D = -1 mA | -0.45 | | -1.5 | V |
| Forward Transfer Admittance Note | y fs | V _{DS} = -10 V, I _D = -3.8 A | 5 | | | S |
| Drain to Source On-state Resistance Note | RDS(on)1 | V _{GS} = -4.5 V, I _D = -7.5 A | | 21 | 25 | mΩ |
| | R _{DS(on)2} | V _{GS} = -2.5 V, I _D = -3.8 A | | 25 | 34 | mΩ |
| | RDS(on)3 | V _{GS} = -1.8 V, I _D = -3.8 A | | 34 | 66 | mΩ |
| Input Capacitance | Ciss | $V_{DS} = -10 \text{ V},$ | | 1350 | | pF |
| Output Capacitance | Coss | V _{GS} = 0 V, | | 255 | | pF |
| Reverse Transfer Capacitance | Crss | f = 1 MHz | | 215 | | pF |
| Turn-on Delay Time | t _{d(on)} | $V_{DD} = -10 \text{ V}, I_D = -3.8 \text{ A},$ | | 10.7 | | ns |
| Rise Time | tr | V _{GS} = -4.0 V, | | 16.7 | | ns |
| Turn-off Delay Time | t _{d(off)} | R _G = 10 Ω | | 101.0 | | ns |
| Fall Time | t f | | | 76.4 | | ns |
| Total Gate Charge | Q _G | V _{DD} = -9.6 V, | | 14.9 | | nC |
| Gate to Source Charge | Qgs | V _{GS} = -4.5 V, | | 2.8 | | nC |
| Gate to Drain Charge | Q _{GD} | I _D = -7.5 A | | 4.0 | | nC |
| Body Diode Forward Voltage Note | V _{F(S-D)} | I _F = -7.5 A, V _{GS} = 0 V | | 0.88 | 1.2 | V |
| Reverse Recovery Time | trr | $I_F = -7.5 \text{ A}, V_{GS} = 0 \text{ V},$ | | 60 | | ns |
| Reverse Recovery Charge | Qrr | $di/dt = -47 \text{ A}/\mu\text{s}$ | | 19 | | nC |

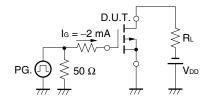
Note Pulsed

TEST CIRCUIT 1 SWITCHING TIME



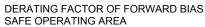


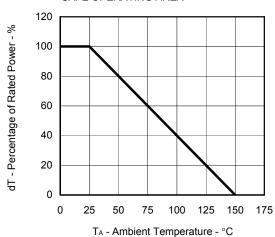
TEST CIRCUIT 2 GATE CHARGE



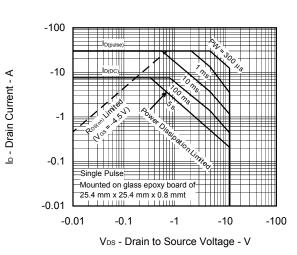
 μ PA2211T1M

TYPICAL CHARACTERISTICS (TA = 25°C)

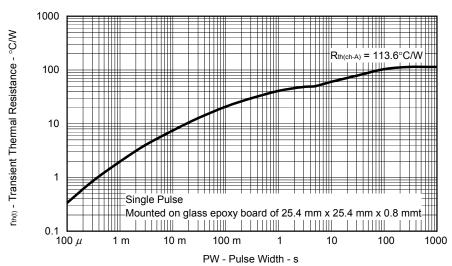




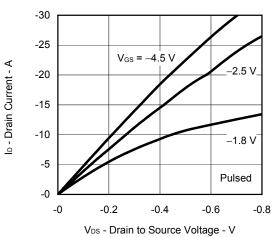
FORWARD BIAS SAFE OPERATING AREA



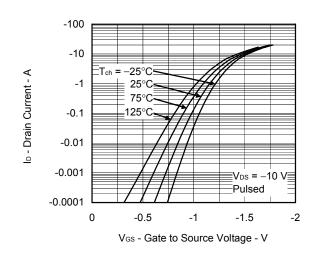
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

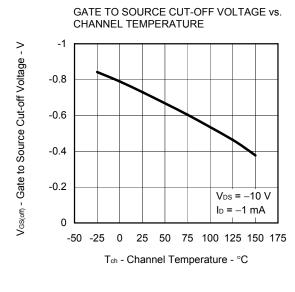


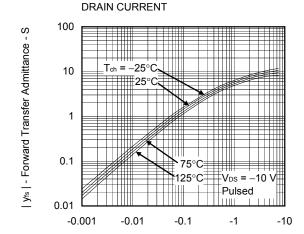
DRAIN CURRENT vs. DRAIN TO SOURCE VOLTAGE



FORWARD TRANSFER CHARACTERISTICS

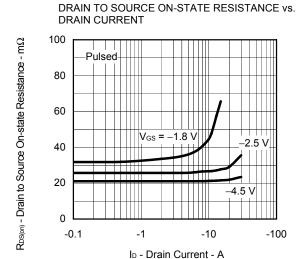


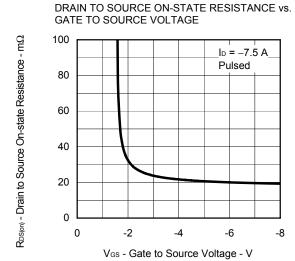


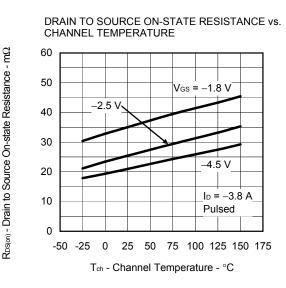


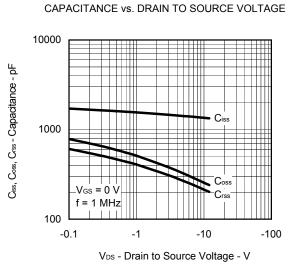
FORWARD TRANSFER ADMITTANCE vs.

ID - Drain Current - A



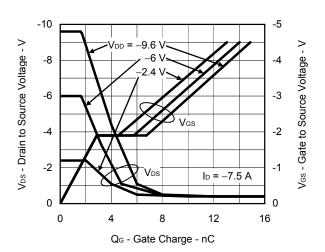




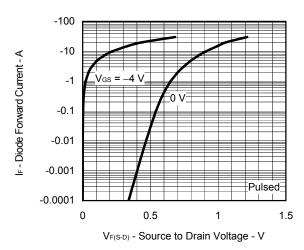


NEC μ PA2211T1M

DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



NEC μ PA2211T1M

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